



# PSMN7R8-120PS

N-channel 120V 7.9mΩ standard level MOSFET in TO220

25 January 2013

Product data sheet

## 1. General description

Standard level N-channel MOSFET in TO220 package qualified to 175°C. This product is designed and qualified for use in a wide range of industrial, communications and power supply equipment.

## 2. Features and benefits

- High efficiency due to low switching and conduction losses
- TO220 package
- Suitable for standard level gate drive

## 3. Applications

- AC-to-DC power supply
- Synchronous rectification
- Motor control

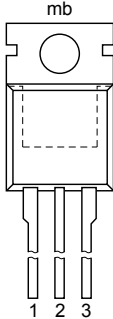
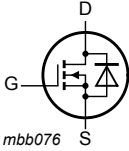
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>J</sub> ≥ 25 °C; T <sub>J</sub> ≤ 175 °C		-	-	120	V
I <sub>D</sub>	drain current	T <sub>mb</sub> = 25 °C; V <sub>GS</sub> = 10 V; <a href="#">Fig. 1</a>		-	-	70	A
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <a href="#">Fig. 2</a>		-	-	349	W
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>J</sub> = 25 °C; <a href="#">Fig. 12</a>		4.7	6.72	7.9	mΩ
Dynamic characteristics							
Q <sub>GD</sub>	gate-drain charge	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; V <sub>DS</sub> = 60 V; <a href="#">Fig. 14</a> ; <a href="#">Fig. 15</a>		-	50.5	-	nC
Q <sub>G(tot)</sub>	total gate charge			-	167	-	nC
Avalanche ruggedness							
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	V <sub>GS</sub> = 10 V; T <sub>J(init)</sub> = 25 °C; I <sub>D</sub> = 70 A; V <sub>sup</sub> ≤ 120 V; unclamped; R <sub>GS</sub> = 50 Ω; <a href="#">Fig. 3</a>		-	-	386	mJ

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	 TO-220AB (SOT78)	 mbb076
2	D	drain		
3	S	source		
mb	D	drain		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN7R8-120PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN7R8-120PS	PSMN7R8-120PS

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$T_j \geq 25\text{ °C}$ ; $T_j \leq 175\text{ °C}$	-	120	V
$V_{DGR}$	drain-gate voltage	$T_j \geq 25\text{ °C}$ ; $T_j \leq 175\text{ °C}$ ; $R_{GS} = 20\text{ k}\Omega$	-	120	V
$V_{GS}$	gate-source voltage		-20	20	V
$I_D$	drain current	$V_{GS} = 10\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; Fig. 1	-	70	A
		$V_{GS} = 10\text{ V}$ ; $T_{mb} = 100\text{ °C}$ ; Fig. 1	-	70	A
$I_{DM}$	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ °C}$ ; Fig. 4	-	280	A

Symbol	Parameter	Conditions		Min	Max	Unit
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <a href="#">Fig. 2</a>		-	349	W
T <sub>stg</sub>	storage temperature			-55	175	°C
T <sub>j</sub>	junction temperature			-55	175	°C
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-drain diode						
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C		-	70	A
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 μs; T <sub>mb</sub> = 25 °C		-	280	A
Avalanche ruggedness						
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	V <sub>GS</sub> = 10 V; T <sub>j(initial)</sub> = 25 °C; I <sub>D</sub> = 70 A; V <sub>sup</sub> ≤ 120 V; unclamped; R <sub>GS</sub> = 50 Ω; <a href="#">Fig. 3</a>		-	386	mJ

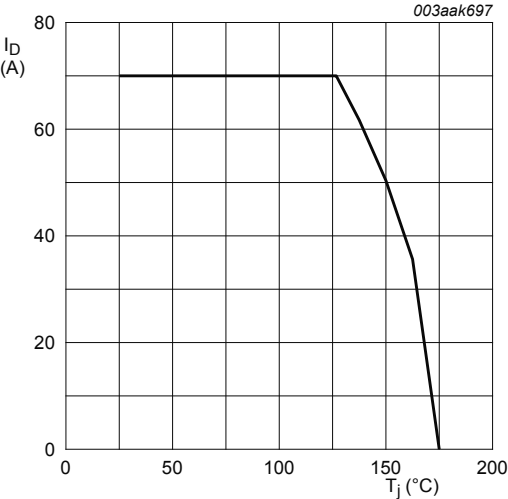


Fig. 1. Continuous drain current as a function of mounting base temperature

$V_{GS} \geq 10V$

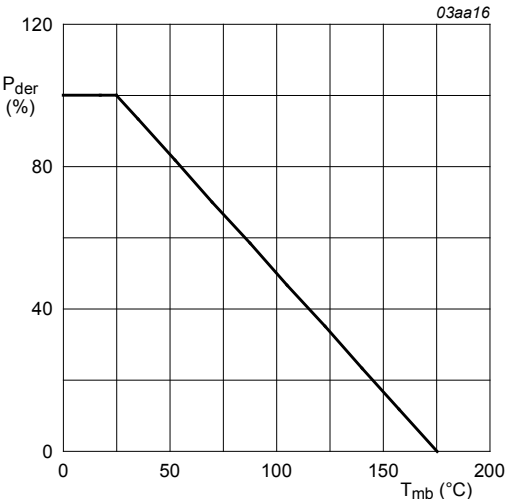


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

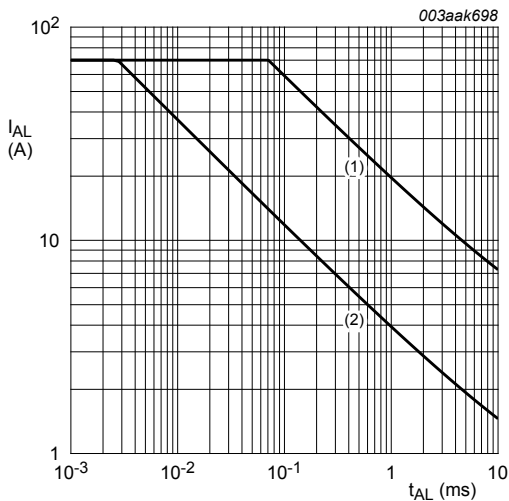


Fig. 3. Single-pulse and repetitive avalanche rating; avalanche current as a function of avalanche time

- (1) Single-pulse;  $T_j = 25\text{ }^{\circ}\text{C}$ .  
(2) Single-pulse;  $T_j = 125\text{ }^{\circ}\text{C}$ .

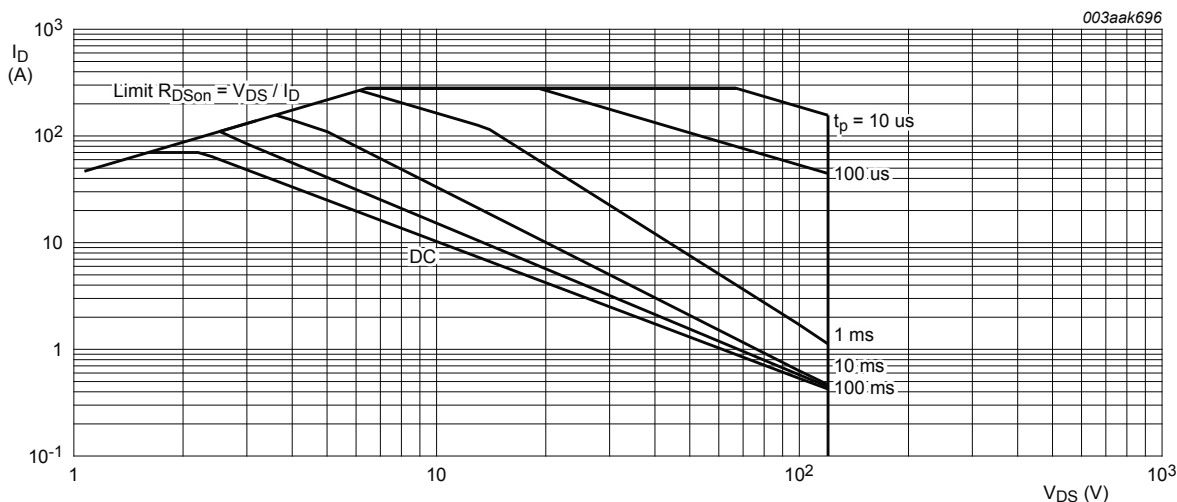


Fig. 4. Safe operating area; continuous and peak drain current as a function of drain-source voltage

$T_{mb} = 25\text{ }^{\circ}\text{C}$ ;  $I_{DM}$  is single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5	-	0.35	0.43	K/W

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in free air	-	60	-	K/W

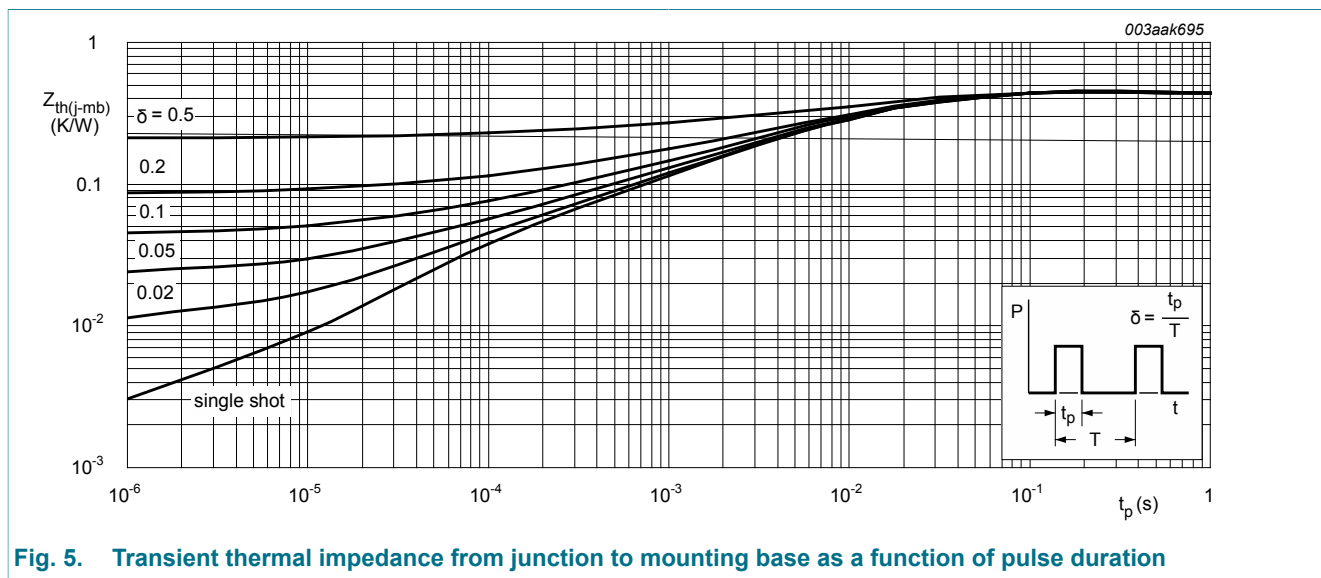


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A$ ; $V_{GS} = 0 V$ ; $T_J = 25 ^\circ C$	120	-	-	V
		$I_D = 250 \mu A$ ; $V_{GS} = 0 V$ ; $T_J = -55 ^\circ C$	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA$ ; $V_{DS} = V_{GS}$ ; $T_J = 25 ^\circ C$ ; <a href="#">Fig. 10</a> ; <a href="#">Fig. 11</a>	2	3	4	V
		$I_D = 1 mA$ ; $V_{DS} = V_{GS}$ ; $T_J = 175 ^\circ C$ ; <a href="#">Fig. 10</a>	1	-	-	V
		$I_D = 1 mA$ ; $V_{DS} = V_{GS}$ ; $T_J = -55 ^\circ C$ ; <a href="#">Fig. 10</a>	-	-	4.6	V
$I_{DSS}$	drain leakage current	$V_{DS} = 120 V$ ; $V_{GS} = 0 V$ ; $T_J = 25 ^\circ C$	-	0.1	1	$\mu A$
		$V_{DS} = 120 V$ ; $V_{GS} = 0 V$ ; $T_J = 175 ^\circ C$	-	-	500	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20 V$ ; $V_{DS} = 0 V$ ; $T_J = 25 ^\circ C$	-	10	100	nA
		$V_{GS} = -20 V$ ; $V_{DS} = 0 V$ ; $T_J = 25 ^\circ C$	-	10	100	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10 V$ ; $I_D = 25 A$ ; $T_J = 25 ^\circ C$ ; <a href="#">Fig. 12</a>	4.7	6.72	7.9	mΩ
		$V_{GS} = 10 V$ ; $I_D = 25 A$ ; $T_J = 175 ^\circ C$ ; <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>	-	19.3	22.9	mΩ

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
R <sub>G</sub>	internal gate resistance (AC)	f = 1 MHz		0.39	0.78	1.56	Ω
Dynamic characteristics							
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 10 V; <a href="#">Fig. 14</a> ; <a href="#">Fig. 15</a>		-	167	-	nC
Q <sub>GS</sub>	gate-source charge			-	36.9	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate-source charge			-	24.2	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate-source charge			-	12.7	-	nC
Q <sub>GD</sub>	gate-drain charge			-	50.5	-	nC
V <sub>GS(pl)</sub>	gate-source plateau voltage	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 60 V; <a href="#">Fig. 14</a> ; <a href="#">Fig. 15</a>		-	4.5	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; <a href="#">Fig. 16</a>		-	9473	-	pF
C <sub>oss</sub>	output capacitance			-	441	-	pF
C <sub>rss</sub>	reverse transfer capacitance			-	298	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 60 V; R <sub>L</sub> = 2.4 Ω; V <sub>GS</sub> = 10 V; R <sub>G(ext)</sub> = 5 Ω; T <sub>j</sub> = 25 °C		-	45.5	-	ns
t <sub>r</sub>	rise time			-	55.3	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	151.8	-	ns
t <sub>f</sub>	fall time			-	60.8	-	ns
Source-drain diode							
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <a href="#">Fig. 17</a>		-	0.81	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 25 A; di <sub>S</sub> /dt = -100 A/μs; V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 60 V		-	75.7	-	ns
Q <sub>r</sub>	recovered charge			-	264	-	nC

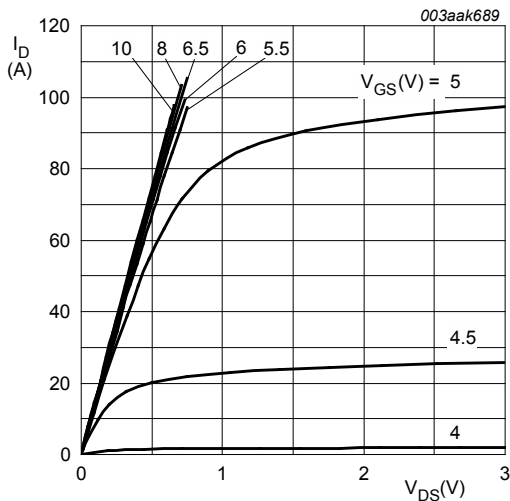


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

$T_j = 25\text{ }^{\circ}\text{C}$

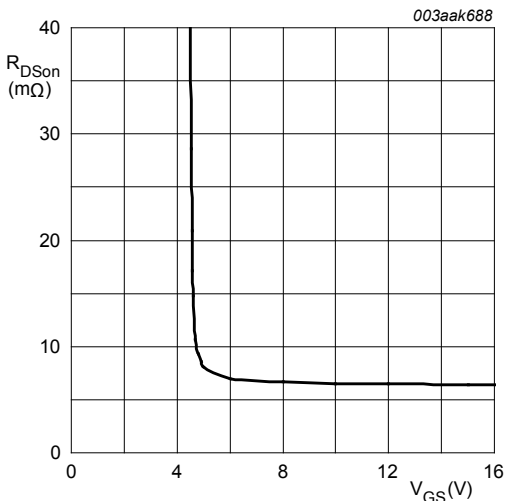


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25\text{ }^{\circ}\text{C}$

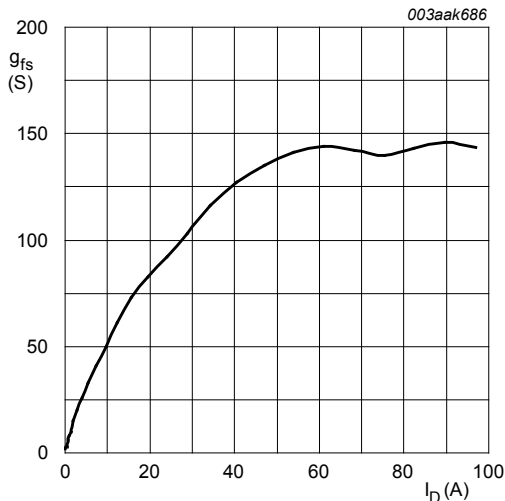


Fig. 8. Forward transconductance as a function of drain current; typical values

$T_j = 25\text{ }^{\circ}\text{C}; V_{DS} = 10\text{ V}$

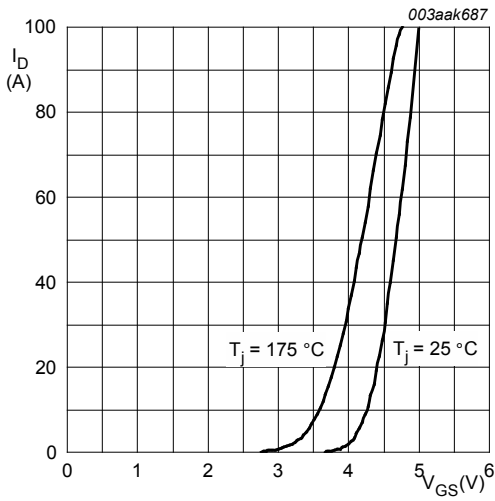


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$V_{DS} > I_D \times R_{DS(on)}$

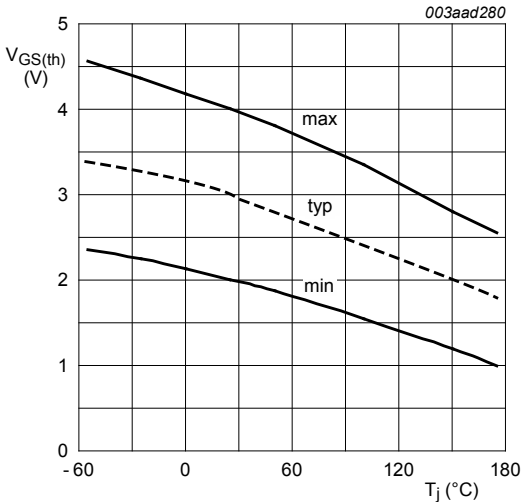


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1\text{ mA}; V_{DS} = V_{GS}$

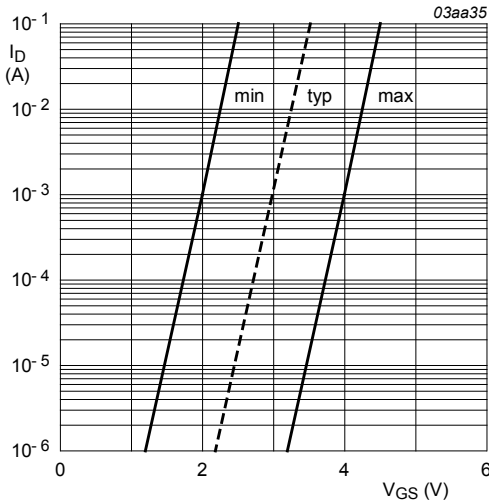


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25^\circ\text{C}; V_{DS} = 5\text{ V}$

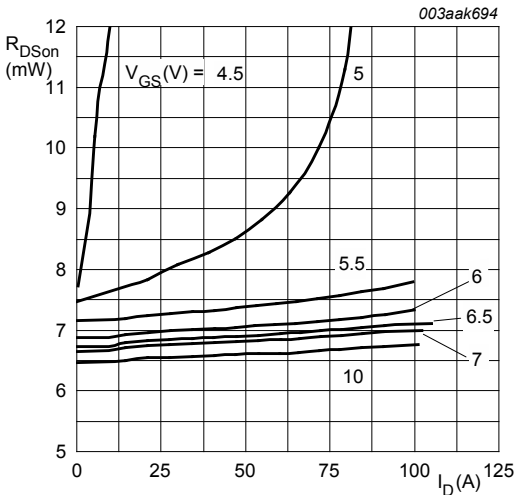


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25^\circ\text{C}$

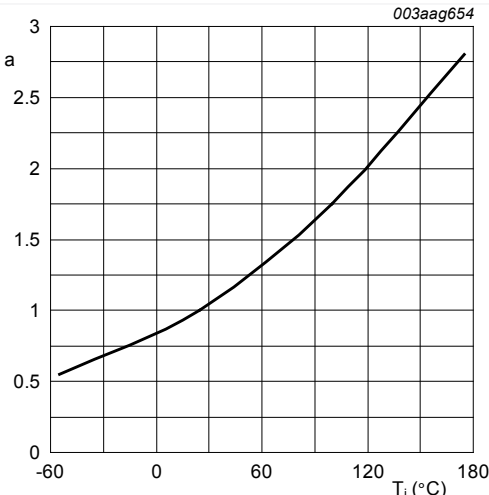


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon(25^\circ\text{C})}}$$



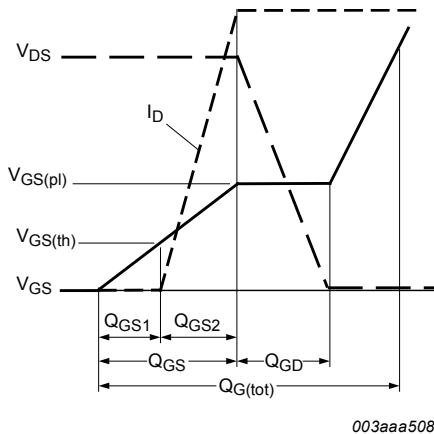


Fig. 14. Gate charge waveform definitions

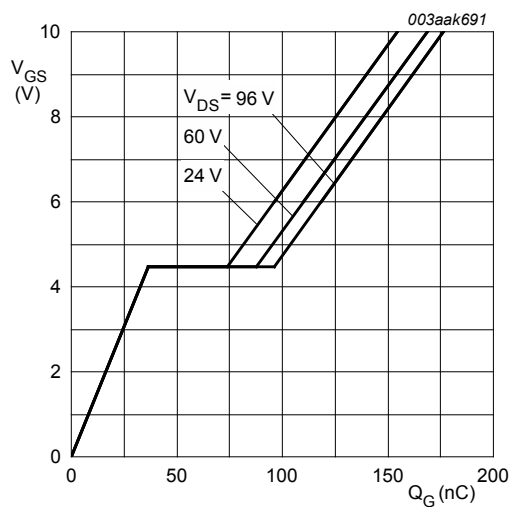


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$T_J = 25\text{ }^{\circ}\text{C}; I_D = 25\text{ A}$

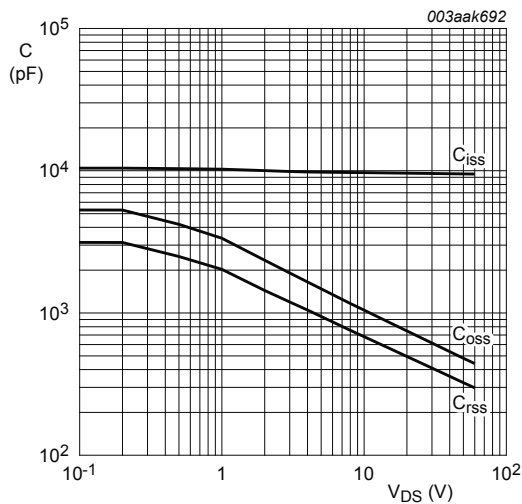


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$

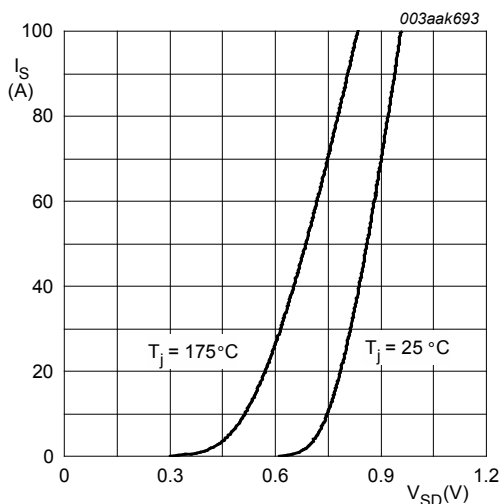


Fig. 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$V_{GS} = 0\text{ V}$

11. Package outline

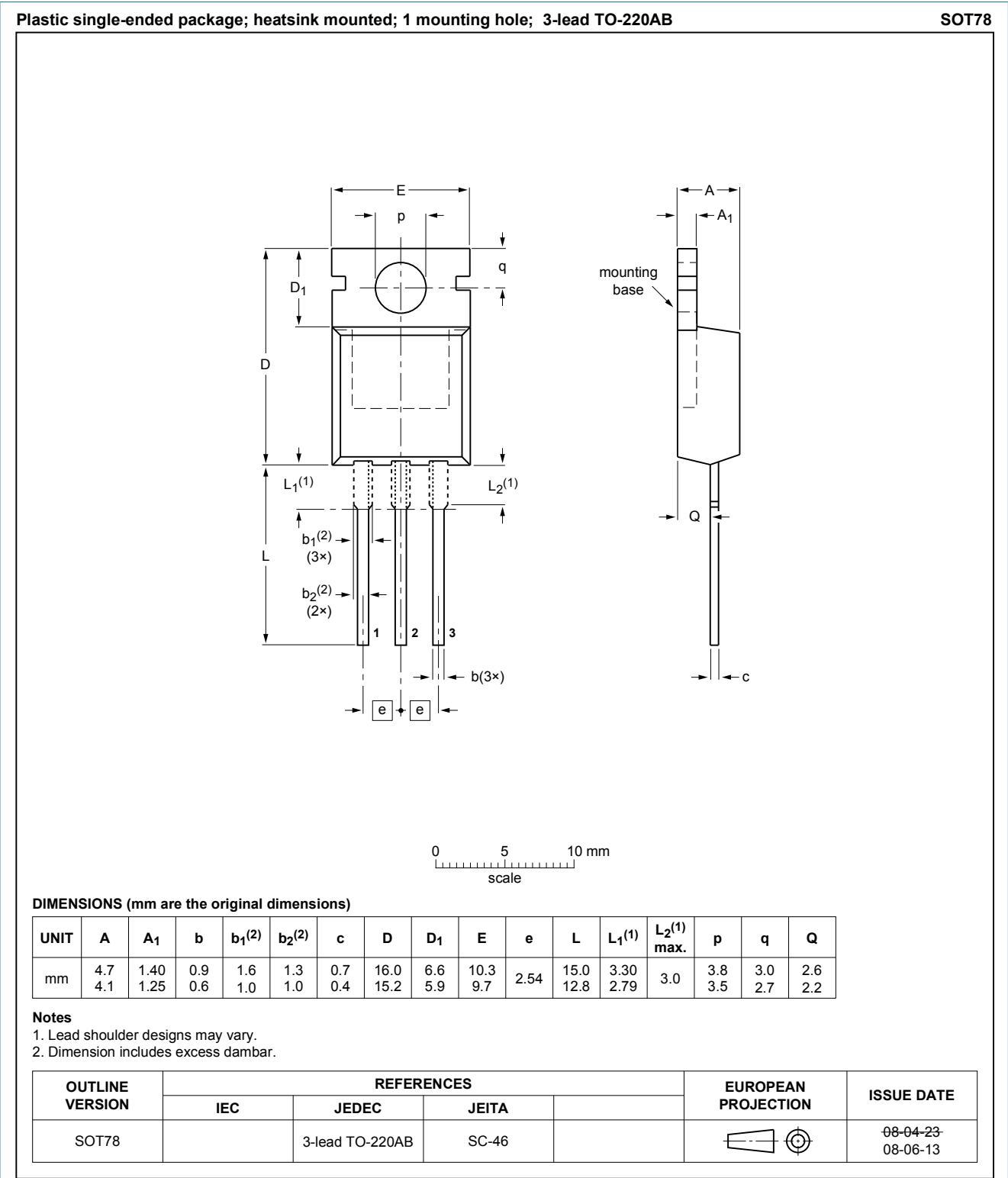


Fig. 18. Package outline TO-220AB (SOT78)

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### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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13. Contents

1	General description .....	1
2	Features and benefits .....	1
3	Applications .....	1
4	Quick reference data .....	1
5	Pinning information .....	2
6	Ordering information .....	2
7	Marking .....	2
8	Limiting values .....	2
9	Thermal characteristics .....	4
10	Characteristics .....	5
11	Package outline .....	10
12	Legal information .....	11
12.1	Data sheet status .....	11
12.2	Definitions .....	11
12.3	Disclaimers .....	11
12.4	Trademarks .....	12

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